NSN 5962-01-159-6494

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-159-6494

Body Length:

1.290 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

0.210 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Glcm bgm-109

Features Provided:

Hermetically sealed and burn in and ultraviolet erasable and programmable and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

11.5 volts power source

Time Rating Per Chacteristic:

600.00 nanoseconds propagation delay time, low to high level output and 600.00 nanoseconds propagation delay time, high to low level output

-- -

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

NSN 5962-01-159-6494

Memory Microcircuit - Page 2 of 2

Fiig: A458a0

